Unit in mm

TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

HN2S01F

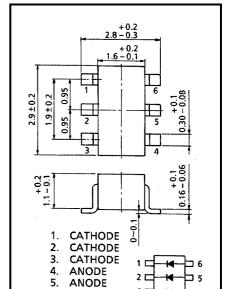
Low Voltage High Speed Switching Application

- HN2S01F is composed of 3 independent diodes.
- Low reverse current: $V_F = 0.23V$ (typ.) @ $I_F = 5mA$

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Maximum (peak) reverse Voltage	V_{RM}	15	V	
Reverse voltage	V _R	10	V	
Maximum (peak) forward current	I _{FM}	200 *	mA	
Average forward current	Io	100 *	mA	
Surge current (10ms)	I _{FSM}	1 *	Α	
Power dissipation	Р	300	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	- 55~125	°C	
Operating temperature range	T _{opr}	- 40~100	°C	

^{* :} This is maximum rating of single diode (Q1 or Q2 or Q3). In the case of using 2 ro 3 diodes, the maximum ratings per diodes is 75 % of the single diode one.



SC-74

1-3K1C

Weight: 0.015g

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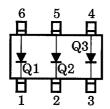
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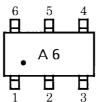
Electrical Characteristics (Q1, Q2, Q3 Common, Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Forward voltage	V _{F (1)}	_	I _F = 1mA	_	0.18	_		
	V _{F (2)}	_	I _F = 5mA	_	0.23	0.30	V	
	V _{F (3)}	_	I _F = 100mA	_	0.35	0.50		
Reverse current	I _R	_	V _R = 10V	_	_	20	μA	
Total capacitance	C _T	_	V _R = 0, f = 1MH _z		20	40	pF	

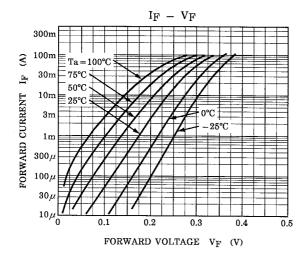
Pin Assignment (Top View)

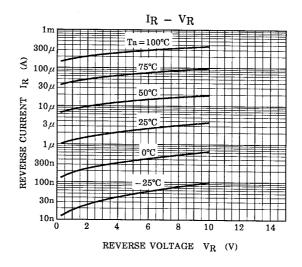
Marking

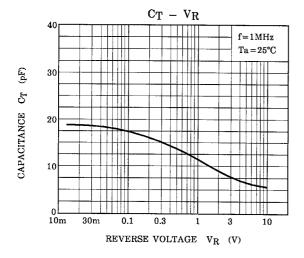


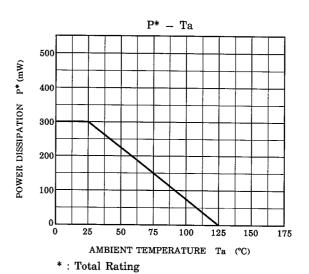


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